

ENGR-2300

Electronic Instrumentation

Quiz 3

Fall 2017

Name SOLUTIONS

Section

Question 1 (20 Points) _____

Question 2 (20 Points) _____

Question 3 (20 Points) _____

Question 4 (20 Points) _____

LMS Question is worth an additional 20pts

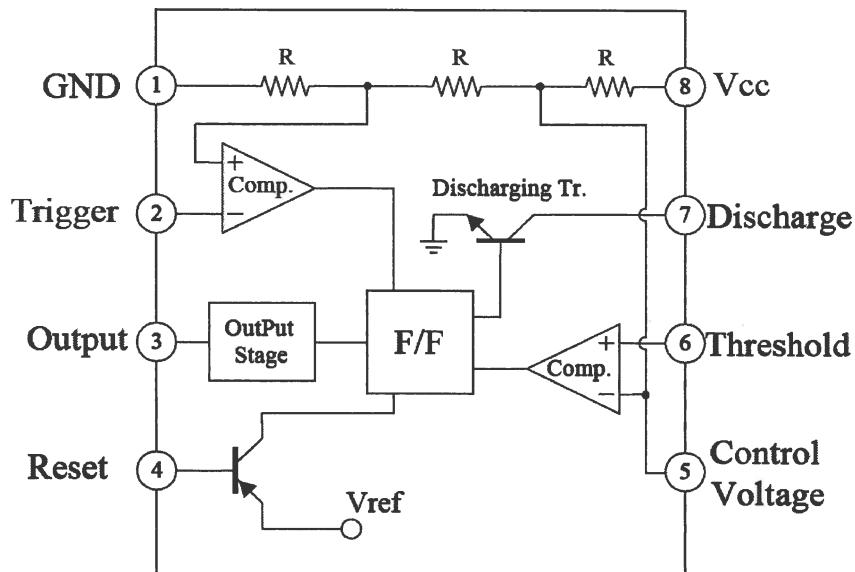
Total (80 points) _____

On all questions: **SHOW ALL WORK. BEGIN WITH FORMULAS, THEN SUBSTITUTE VALUES AND UNITS.** No credit will be given for answers that appear without justification. Read the entire quiz before answering any questions. Also it may be easier to answer parts of questions out of order.

Some Additional Background plus

| Standard Resistor Values ($\pm 5\%$) | | | | | | |
|--|----|-----|------|-----|------|------|
| 1.0 | 10 | 100 | 1.0K | 10K | 100K | 1.0M |
| 1.1 | 11 | 110 | 1.1K | 11K | 110K | 1.1M |
| 1.2 | 12 | 120 | 1.2K | 12K | 120K | 1.2M |
| 1.3 | 13 | 130 | 1.3K | 13K | 130K | 1.3M |
| 1.5 | 15 | 150 | 1.5K | 15K | 150K | 1.5M |
| 1.6 | 16 | 160 | 1.6K | 16K | 160K | 1.6M |
| 1.8 | 18 | 180 | 1.8K | 18K | 180K | 1.8M |
| 2.0 | 20 | 200 | 2.0K | 20K | 200K | 2.0M |
| 2.2 | 22 | 220 | 2.2K | 22K | 220K | 2.2M |
| 2.4 | 24 | 240 | 2.4K | 24K | 240K | 2.4M |
| 2.7 | 27 | 270 | 2.7K | 27K | 270K | 2.7M |
| 3.0 | 30 | 300 | 3.0K | 30K | 300K | 3.0M |
| 3.3 | 33 | 330 | 3.3K | 33K | 330K | 3.3M |
| 3.6 | 36 | 360 | 3.6K | 36K | 360K | 3.6M |
| 3.9 | 39 | 390 | 3.9K | 39K | 390K | 3.9M |
| 4.3 | 43 | 430 | 4.3K | 43K | 430K | 4.3M |
| 4.7 | 47 | 470 | 4.7K | 47K | 470K | 4.7M |
| 5.1 | 51 | 510 | 5.1K | 51K | 510K | 5.1M |
| 5.6 | 56 | 560 | 5.6K | 56K | 560K | 5.6M |
| 6.2 | 62 | 620 | 6.2K | 62K | 620K | 6.2M |
| 6.8 | 68 | 680 | 6.8K | 68K | 680K | 6.8M |
| 7.5 | 75 | 750 | 7.5K | 75K | 750K | 7.5M |
| 8.2 | 82 | 820 | 8.2K | 82K | 820K | 8.2M |
| 9.1 | 91 | 910 | 9.1K | 91K | 910K | 9.1M |

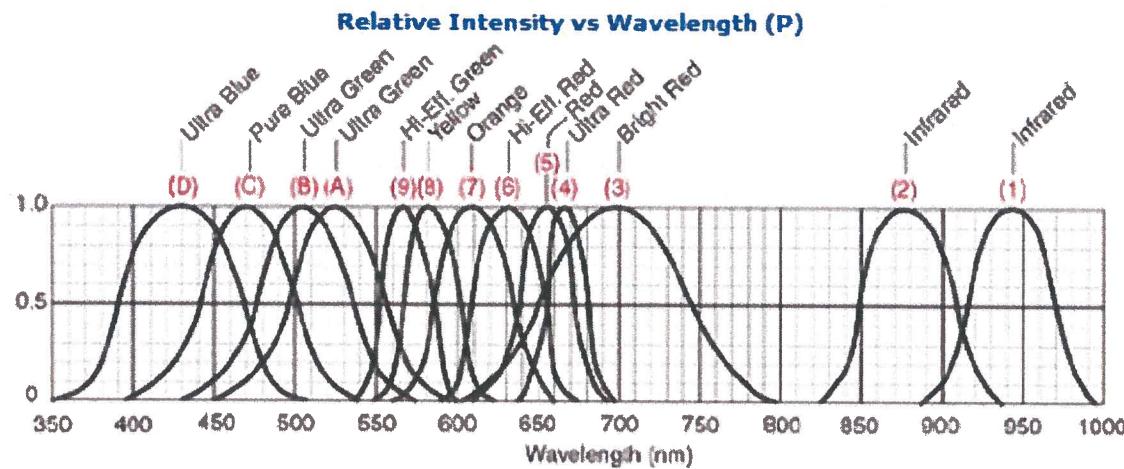
555 Timer Block Diagram



Zener Diodes: From Wikipedia: A **Zener diode** is a diode which allows current to flow in the forward direction in the same manner as an ideal diode, but also permits it to flow in the reverse direction when the voltage is above a certain value known as the breakdown voltage, "zener knee voltage", "zener voltage", "avalanche point", or "peak inverse voltage".

The device was named after Clarence Zener, who discovered this electrical property. Many diodes described as "zener" diodes rely instead on avalanche breakdown as the mechanism. Both types are used. Common applications include providing a reference voltage for voltage regulators, or to protect other semiconductor devices from momentary voltage pulses.

| Type Number | Nominal Zener Voltage $V_Z @ I_{ZT}^{(1)}$ (Volts) | Test Current I_{ZT} (mA) | Maximum Zener Impedance $Z_{ZT} @ I_{ZT}^{(1)}$ (Ω) | Maximum Regulator Current $I_{ZR}^{(2)}$ (mA) | Maximum Reverse Leakage Current | |
|-------------|--|----------------------------|--|---|---|--|
| | | | | | $T_A = 25^\circ\text{C}$ $I_R @ V_R = 1\text{V}$ (μA) | $T_A = 150^\circ\text{C}$ $I_R @ V_R = 1\text{V}$ (μA) |
| 1N746A | 3.3 | 20 | 28 | 110 | 10 | 30 |
| 1N747A | 3.6 | 20 | 24 | 100 | 10 | 30 |
| 1N748A | 3.9 | 20 | 23 | 95 | 10 | 30 |
| 1N749A | 4.3 | 20 | 22 | 85 | 2 | 30 |
| 1N750A | 4.7 | 20 | 19 | 75 | 2 | 30 |
| 1N751A | 5.1 | 20 | 17 | 70 | 1 | 20 |
| 1N752A | 5.6 | 20 | 11 | 65 | 1 | 20 |
| 1N753A | 6.2 | 20 | 7 | 60 | 0.1 | 20 |
| 1N754A | 6.8 | 20 | 5 | 55 | 0.1 | 20 |
| 1N755A | 7.5 | 20 | 6 | 50 | 0.1 | 20 |
| 1N756A | 8.2 | 20 | 8 | 45 | 0.1 | 20 |
| 1N757A | 9.1 | 20 | 10 | 40 | 0.1 | 20 |
| 1N758A | 10 | 20 | 17 | 35 | 0.1 | 20 |
| 1N759A | 12 | 20 | 30 | 30 | 0.1 | 20 |

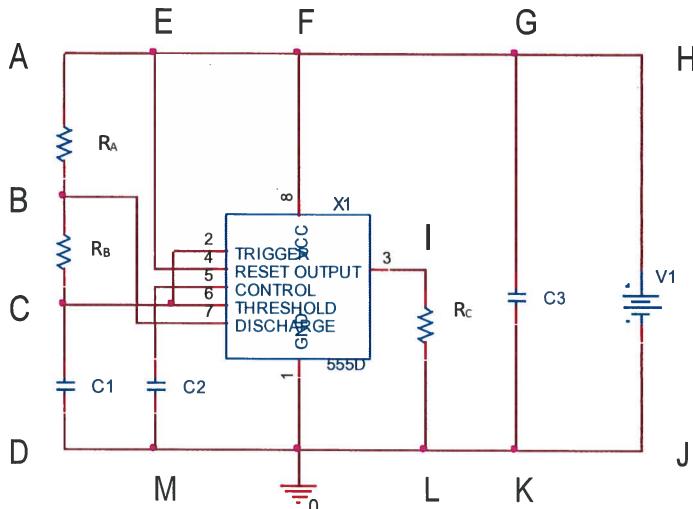


| | Wavelength (nm) | Color Name | Fwd Voltage (Vf @ 20mA) | Intensity 5mm LEDs | Viewing Angle | LED Dye Material |
|--|------------------------|----------------------|--------------------------------|---------------------------|----------------------|--|
| | 940 | Infrared | 1.5 | 16mW @50mA | 15° | GaAlAs/GaAs -- Gallium Aluminum Arsenide/Gallium Arsenide |
| | 880 | Infrared | 1.7 | 18mW @50mA | 15° | GaAlAs/GaAs -- Gallium Aluminum Arsenide/Gallium Arsenide |
| | 850 | Infrared | 1.7 | 26mW @50mA | 15° | GaAlAs/GaAs -- Gallium Aluminum Arsenide/Gallium Aluminum Arsenide |
| | 660 | Ultra Red | 1.8 | 2000mcd @50mA | 15° | GaAlAs/GaAs -- Gallium Aluminum Arsenide/Gallium Aluminum Arsenide |
| | 635 | High Eff. Red | 2.0 | 200mcd @20mA | 15° | GaAsP/GaP - Gallium Arsenic Phosphide / Gallium Phosphide |
| | 633 | Super Red | 2.2 | 3500mcd @20mA | 15° | InGaAIP - Indium Gallium Aluminum Phosphide |
| | 620 | Super Orange | 2.2 | 4500mcd @20mA | 15° | InGaAIP - Indium Gallium Aluminum Phosphide |
| | 612 | Super Orange | 2.2 | 6500mcd @20mA | 15° | InGaAIP - Indium Gallium Aluminum Phosphide |
| | 605 | Orange | 2.1 | 160mcd @20mA | 15° | GaAsP/GaP - Gallium Arsenic Phosphide / Gallium Phosphide |
| | 595 | Super Yellow | 2.2 | 5500mcd @20mA | 15° | InGaAIP - Indium Gallium Aluminum Phosphide |
| | 592 | Super Pure Yellow | 2.1 | 7000mcd @20mA | 15° | InGaAIP - Indium Gallium Aluminum Phosphide |
| | 585 | Yellow | 2.1 | 100mcd @20mA | 15° | GaAsP/GaP - Gallium Arsenic Phosphide / Gallium Phosphide |
| | 4500K | "Incandescent" White | 3.6 | 2000mcd @20mA | 20° | SiC/GaN -- Silicon Carbide/Gallium Nitride |

| | | | | | | |
|--|-------|-----------------------|-----|-----------------|-----|--|
| | 6500K | Pale White | 3.6 | 4000mcd @20mA | 20° | SiC/GaN -- Silicon Carbide/Gallium Nitride |
| | 8000K | Cool White | 3.6 | 6000mcd @20mA | 20° | SiC/GaN - Silicon Carbide / Gallium Nitride |
| | 574 | Super Lime Yellow | 2.4 | 1000mcd @20mA | 15° | InGaAIP - Indium Gallium Aluminum Phosphide |
| | 570 | Super Lime Green | 2.0 | 1000mcd @20mA | 15° | InGaAIP - Indium Gallium Aluminum Phosphide |
| | 565 | High Efficiency Green | 2.1 | 200mcd @20mA | 15° | GaP/GaP - Gallium Phosphide/Gallium Phosphide |
| | 560 | Super Pure Green | 2.1 | 350mcd @20mA | 15° | InGaAIP - Indium Gallium Aluminum Phosphide |
| | 555 | Pure Green | 2.1 | 80mcd @20mA | 15° | GaP/GaP - Gallium Phosphide/ Gallium Phosphide |
| | 525 | Aqua Green | 3.5 | 10,000mcd @20mA | 15° | SiC/GaN - Silicon Carbide / Gallium Nitride |
| | 505 | Blue Green | 3.5 | 2000mcd @20mA | 45° | SiC/GaN - Silicon Carbide / Gallium Nitride |
| | 470 | Super Blue | 3.6 | 3000mcd @20mA | 15° | SiC/GaN - Silicon Carbide / Gallium Nitride |
| | 430 | Ultra Blue | 3.8 | 100mcd @20mA | 15° | SiC/GaN - Silicon Carbide / Gallium Nitride |

Question 1 (20 Points) Astable Multivibrator (An Iconic 555 Timer Application)

A 555 timer, astable multivibrator is built as shown with R_A = unknown, R_B = unknown, $R_C = 33k\Omega$, $C_1 = 10\mu F$, $C_2 = 0.01\mu F$, $C_3 = 330\mu F$, and $V_1 = 15V$.



- a. (4 pts) Determine the **maximum and minimum voltages** at pins 2,6 (C). Assume that the circuit is in steady state. You may want to look at the background information at the beginning of this exam.

Trigger at $\frac{V_1}{3}$ and $\frac{2V_1}{3}$

$$V_{min} = 5V \quad V_{max} = 10V$$

- b. (5 pts) The voltage at pin 7 (B) is 0V when the capacitor C_1 discharges through R_B as shown on 555 timer block diagram on page 2 and crib sheet. You are provided with two voltages measured at pin 7 (B) during the charge cycle of capacitor C_1 as 13V (when C_1 is at max voltage) and 11V (when C_1 is at min voltage). Note that voltage at pin 7 is the sum of voltage across R_B and voltage across capacitor C_1 . Find the ratio of resistors R_A/R_B .

$$\text{Voltage at Pin 7} = V_7$$

Using any one given
Voltage at pin 7,

$$13V = 10V + V_{RB}$$

$$V_{RB} = (15 - 10) \cdot \frac{R_B}{R_A + R_B} = \frac{5R_B}{R_A + R_B}$$

$$V_7 = V_{RB} + V_{C1} \rightarrow 10V \text{ and } 5V \\ (From part a.)$$

$$13R_A + 13R_B = 10R_A + 10R_B + 5R_B$$

$$3R_A = 2R_B \Rightarrow$$

$$\boxed{\frac{R_A}{R_B} = \frac{2}{3}}$$

- c. (4 pts) Given $R_A=5k\Omega$ and using results from previous parts, find the **frequency (f)**, **on time (T₁)** and **off time (T₂)** of the timing signal generated on pin 3 (I).

$$R_A = 5k\Omega \text{ (given)}$$

$$R_B = \frac{3R_A}{2} = 7.5k\Omega \text{ (using part b.)}$$

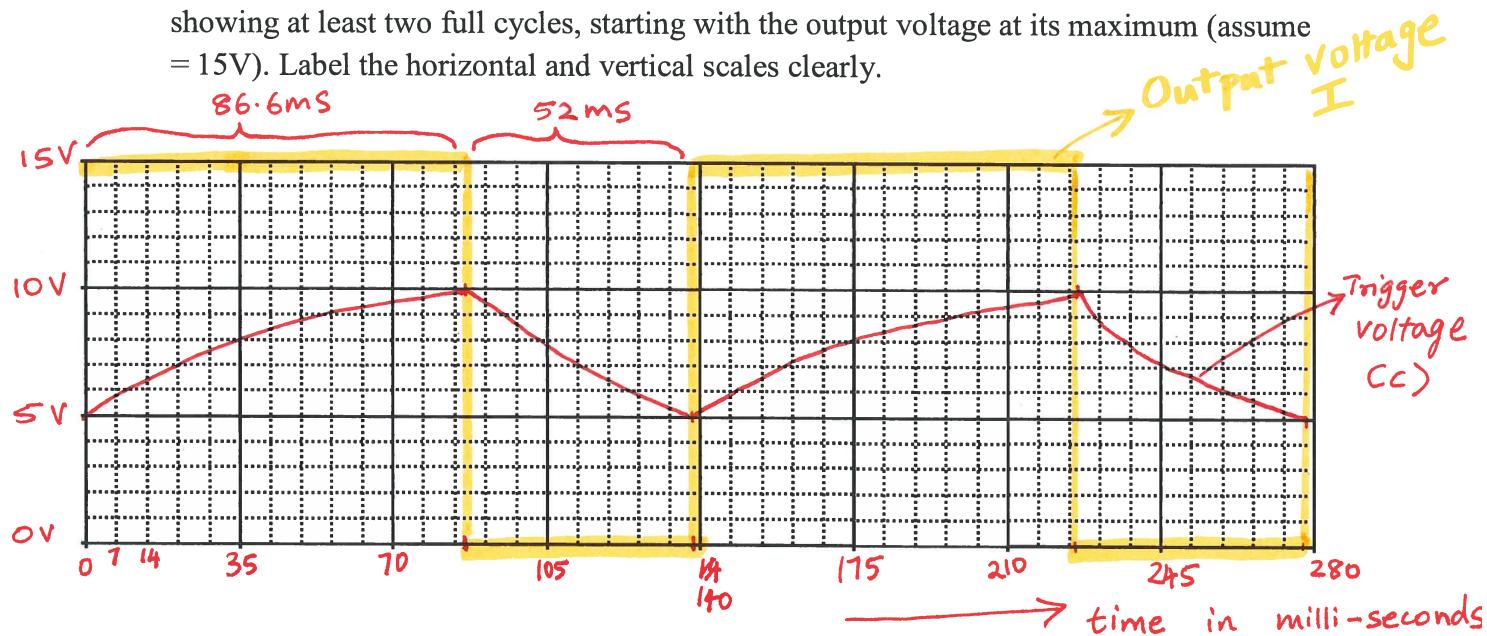
$$C_1 = 10\mu F \text{ (given)}$$

$$T_{OFF} = 0.693 R_B C_1 \\ = 52 \text{ ms}$$

$$\text{frequency } f = \frac{1.44}{(R_A + 2R_B) C_1} \\ = 7.2 \text{ Hz}$$

$$T_{ON} = 0.693 (R_A + R_B) C_1 \\ = 86.6 \text{ ms}$$

- d. (3 pts) Plot the output voltage (**I**) and the trigger voltage measured at pins 2,6 (**C**) below, showing at least two full cycles, starting with the output voltage at its maximum (assume = 15V). Label the horizontal and vertical scales clearly.



Use the table below to answer part e and part f.

| | |
|------------------|------------------|
| A: Increasing R1 | B: Decreasing R1 |
| C: Increasing R2 | D: Decreasing R2 |
| E: Increasing C | F: Decreasing C |

- e. (2 pts) When considering the 555 Timer circuit and the above list of possibilities, holding all other values constant, the **period** can be **increased** by (indicated all correct possibilities)

(list of letters): A, C, E

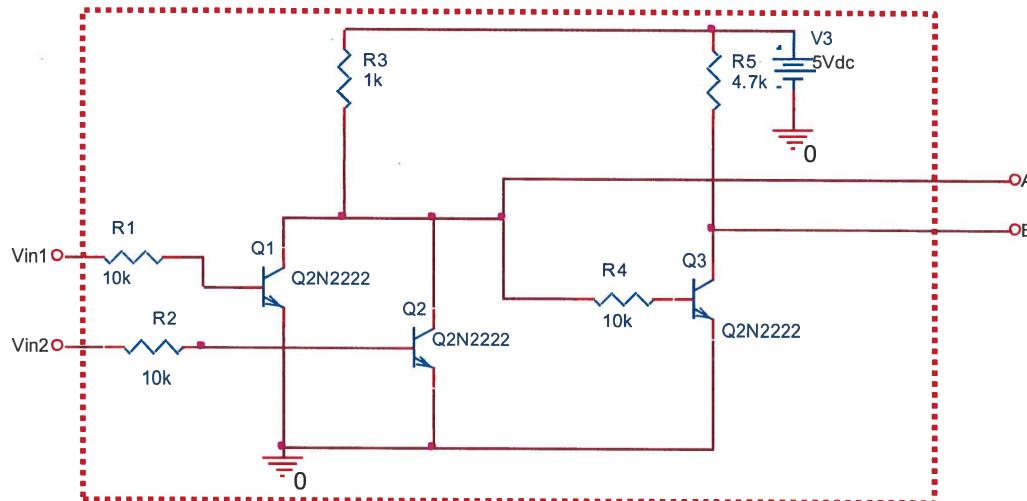
- f. (2 pts) When considering the 555 Timer circuit and the above list of possibilities, holding all other values constant, the **duty cycle** can be **increased** by (indicated all correct possibilities)

(list of letters): A, D

$$D = \frac{R_1 + R_2}{R_1 + 2R_2} \times 100$$

Question 2 (20 Points) Combinational & Sequential Logic Circuits

- a. The circuit below shows how a simple logic gate can be built out of transistors and resistors. The circuit is inside the dashed box and has two inputs and two outputs. Voltages above 2.5V are logic high and voltages below 2.5V are logic low.



- i. (6 pts) Complete the table below using logic levels of 0 and 1, not the actual voltages.

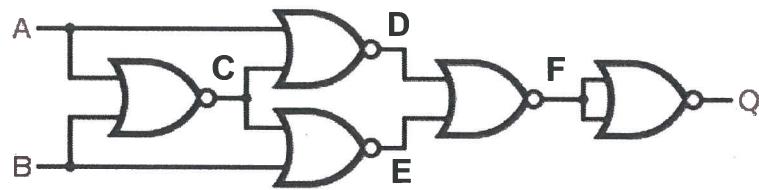
| Vin2 | Vin1 | A | B |
|------|------|---|---|
| 0 | 0 | 1 | 0 |
| 0 | 1 | 0 | 1 |
| 1 | 0 | 0 | 1 |
| 1 | 1 | 0 | 1 |

$$\begin{aligned}
 A &= V_{in1} \text{ NOR } V_{in2} \\
 B &= \text{NOT}(A) \\
 &= V_{in1} \text{ OR } V_{in2}
 \end{aligned}$$

- ii. (2 pts) What type of logic gate does output A represent? What type of logic gate does output B represent?

A represents NOR gate
B represents OR gate

- b. (6 Pts) The following circuit is configured using only NOR gates. Fill in columns C, D, E, F, and Q in the truth table for this circuit. What type of logic gate does output Q represent?



XOR
gate

| Input A | Input B | C | D | E | F | Output Q |
|---------|---------|---|---|---|---|----------|
| 0 | 0 | 1 | 0 | 0 | 1 | 0 |
| 0 | 1 | 0 | 1 | 0 | 0 | 1 |
| 1 | 0 | 0 | 0 | 1 | 0 | 1 |
| 1 | 1 | 0 | 0 | 0 | 1 | 0 |

$C = \overline{A+B}$ $D = \overline{A+C}$ $E = \overline{B+C}$ $F = \overline{D+E}$ $Q = \overline{F}$

- c. (2 pts) A 4-bit counter had an initial state listed as the start state in the table below, and then receives a string of clock pulses. What are QA, QB, QC and QD after 14 clock pulses? Clearly indicate the state of each signal. (2pts)

| | QD | QC | QB | QA |
|-----------------------|----|----|----|----|
| Start state | 0 | 1 | 0 | 1 |
| State after 14 counts | 0 | 0 | 1 | 1 |

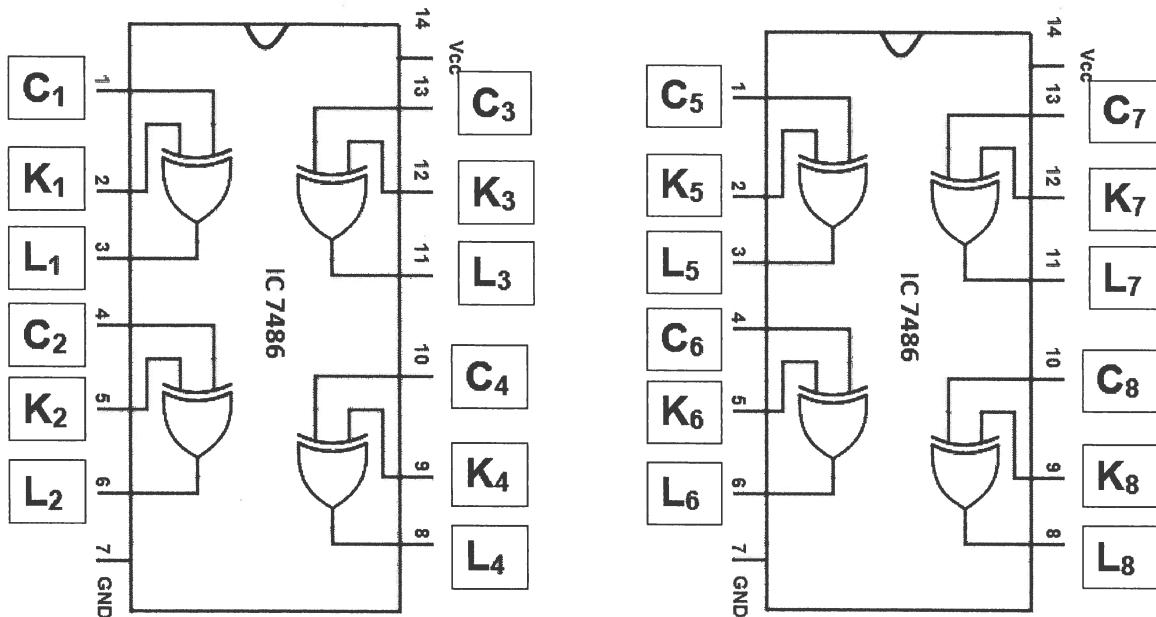
0101 (binary) = 5 (decimal)

Counting sequence starting 5 is 6, 7, 8, ..., 15, 0, 1, 2, 3

3 (decimal) = 0011 (binary)

after 14 counts

- d. (4 pts) XOR Gate Cryptography – Two sets of XOR gates are used to encrypt an ASCII letter. The 8 bit code is $[C_1 \ C_2 \ C_3 \ C_4 \ C_5 \ C_6 \ C_7 \ C_8] = [00011000]$ and the 8 bit key is $[K_1 \ K_2 \ K_3 \ K_4 \ K_5 \ K_6 \ K_7 \ K_8] = [01010111]$. Given that a coded word is known except for two missing letters **B O O L E** and that the missing letters are the same, find the letter. That is, input the 8 bits of the coded letter and the key one-by-one in the eight XOR gates to decode the letter into $[L_1 \ L_2 \ L_3 \ L_4 \ L_5 \ L_6 \ L_7 \ L_8]$. Then use the ASCII table to identify the letter.



| ASCII Alphabet | | | |
|----------------|----------|---|----------|
| A | 01000001 | N | 01001110 |
| B | 01000010 | O | 01001111 |
| C | 01000011 | P | 01010000 |
| D | 01000100 | Q | 01010001 |
| E | 01000101 | R | 01010010 |
| F | 01000110 | S | 01010011 |
| G | 01000111 | T | 01010100 |
| H | 01001000 | U | 01010101 |
| I | 01001001 | V | 01010110 |
| J | 01001010 | W | 01010111 |
| K | 01001011 | X | 01011000 |
| L | 01001100 | Y | 01011001 |
| M | 01001101 | Z | 01011010 |

$$L_i = C_i \oplus K_i$$

↑
XOR

$$\begin{array}{r}
 0 \ 0 \ 0 \ 1 \ 1 \ 0 \ 0 \ 0 \\
 0 \ 1 \ 0 \ 1 \ 0 \ 1 \ 1 \ 1 \\
 \hline
 0 \ 1 \ 0 \ 0 \ 1 \ 1 \ 1
 \end{array}$$

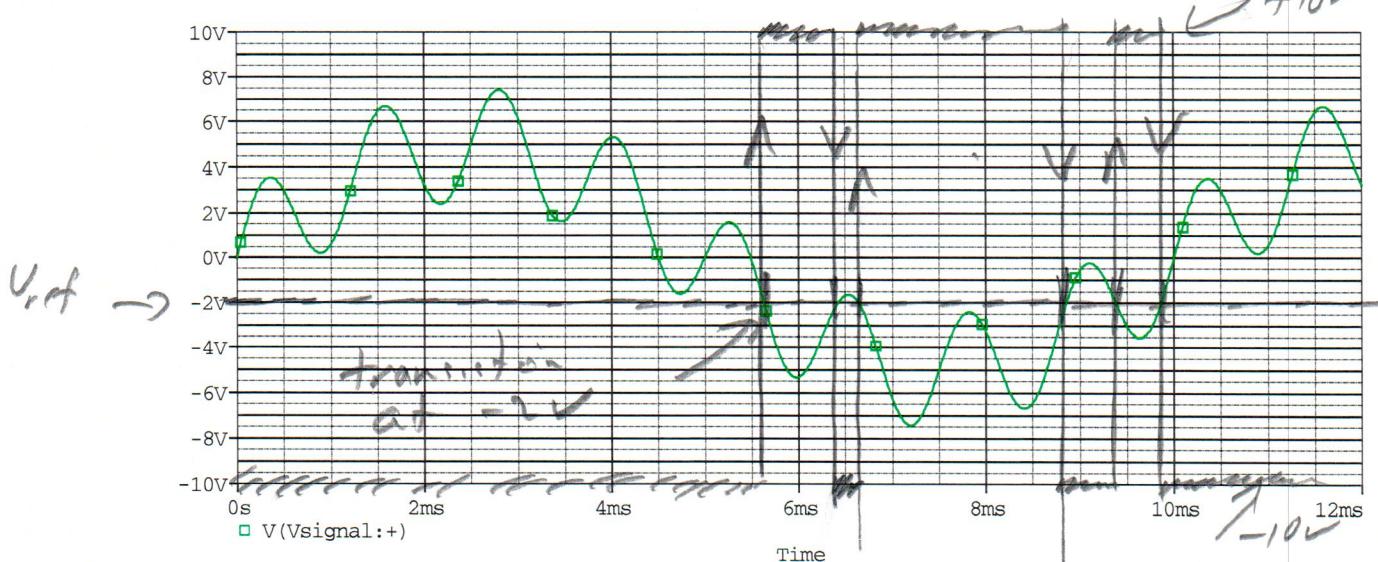
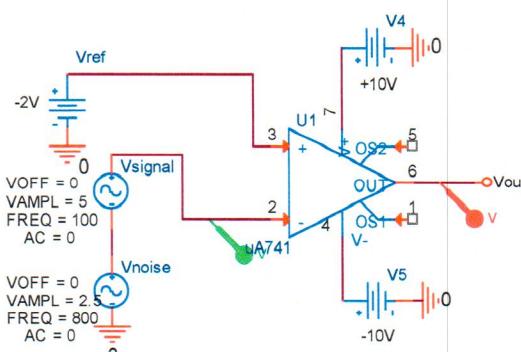
Letter
 O
 from ASCII
 table .

E I

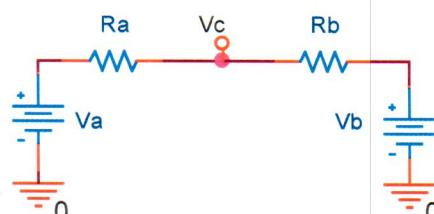
Question 3 (20 Points) Schmitt Trigger

In this problem, we investigate the same properties of Schmitt Triggers we did in Experiment 6. Assume the output of the op-amps is capable of reaching the power supply voltages.

- a. For the circuit shown the input signal, V_{signal} is compared to V_{ref} . The input is corrupted with noise, V_{noise} . The combined V_{signal} plus V_{noise} is shown on the plot. Add a trace for V_{out} . Be sure to mark important voltages. (3pts)



- b. For this circuit shown, assume that V_a , V_b , R_a , and R_b have known values. Write an equation that gives V_c as a function of those values. (3pts)



$$V_C = \frac{R_a}{R_a + R_b} (V_b - V_a) + V_a$$

$$\frac{R_a}{R_a + R_b} (V_b - V_a) + V_a = V_C$$

$$V_c = \left(\frac{R_b}{R_a + R_b} \right) (V_a - V_b) + V_b$$

- c. Complete the table below: (4pts)

| Va | Vb | Ra(Ohms) | Rb(Ohms) | Vc |
|-----|------|----------|----------|-------|
| -2V | +10V | 2k | 6k | IV |
| -2V | -10V | 2k | 6k | -4V |
| -2V | +10V | 1k | 9k | -0.9V |
| -2V | -10V | 1k | 9k | -2.8V |

$$\frac{R_9}{R_9 + R_3} = \frac{1}{3}$$

R_a

$$\text{Ans} = 10 \quad \text{E}$$

E I

12

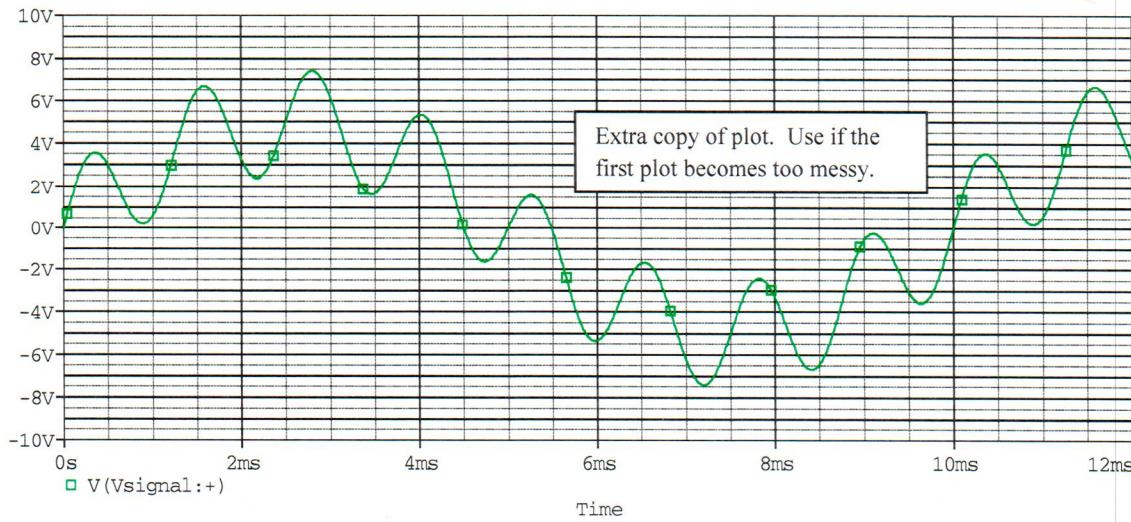
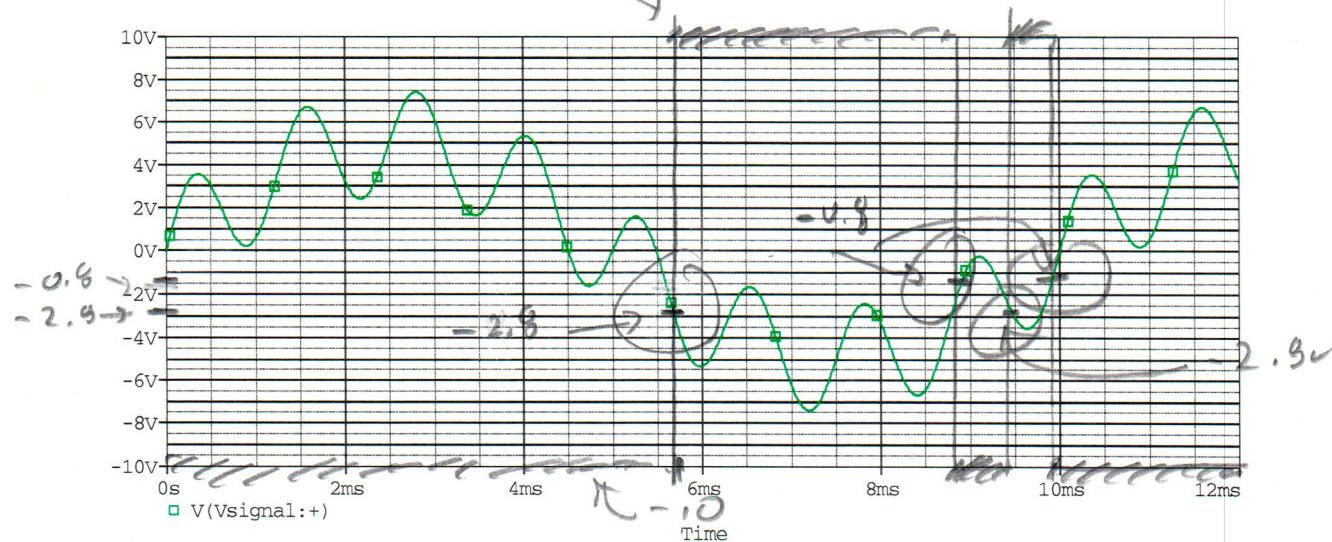
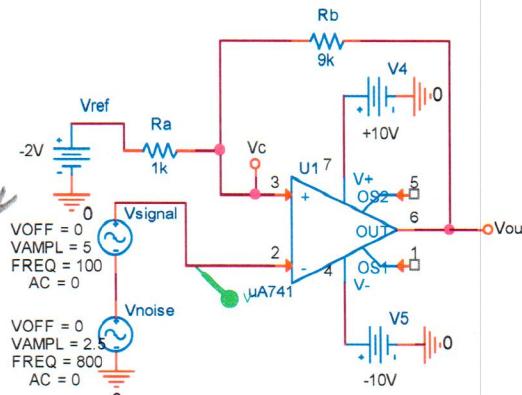
$$\left(\frac{1}{12}\right) \times (10 : (-2))$$

P. M. Schoch and M. A. Hameed

$$\left(\frac{1}{12}\right)\left(10 - (-2)\right) + (-2) = -0.8 \quad \frac{1}{12}(-9) + (-2) = -2.3$$

- d. Results from part b. are useful for this part. Given the circuit shown with an input signal plus unwanted noise. The sum of the signal plus noise have been plotted. On the plot draw both V_c and V_{out} . Label voltage levels. (6pts)

Trigger Voltages are $-0.8V + -2.5V$



- e. Did the circuit in part d. eliminate all false transitions caused by noise? (2pts)

NO

- f. If the circuit used $R_a=2k$ and $R_b=6k$ (table in part c) would the comparator be (circle one) (2pts)

More noise immune

Less noise immune

Not change

Question 4 (20 Points) Diode Circuits

- a. (6pts) In the circuit shown:

$$V_1 = 10V$$

$$R_1 = 200\Omega$$

$$R_{load} = 2k\Omega$$

D1 is a Zener. Three different Zener diodes are tried with this circuit. Determine Vout and the Iz (the current in the Zener) for each case. Use the "Some Additional Background" information at the beginning of this exam.

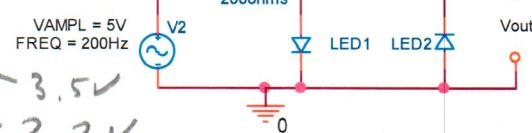
$$I_2 = I_R - I_{R_{load}}$$

$$\frac{10 - 3.3}{0.2} - 1.65 = 31.9mA$$

$$\frac{10 - 6.2}{0.2} - 3.1mA = 15.9mA$$

Vout must be less than 10V

Zener off

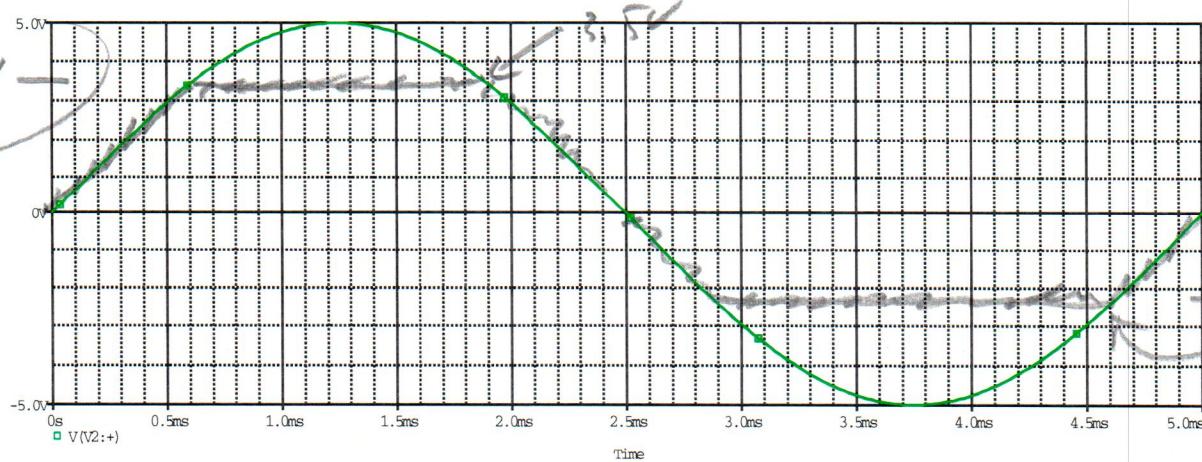


| Zener part number | Vout | Iz |
|-------------------|------|-----------------|
| 1N746A | 3.3V | 31.9mA / 1.65mA |
| 1N753A | 6.2V | 15.9mA / 3.1mA |
| 1N758A | 10V | 0mA |

- b. The circuit shown is a type of Limiter circuit but it uses LEDs rather than diodes for the limiting.

- i. (3pts) Given: LED1 is an Aqua Green LED (525 nm) and LED2 is a Super Red LED (633 nm), sketch Vout below. V2 is already plotted. Use the background info given in this exam.

$$\frac{9.0V}{0.2 + \frac{2}{2.2}} = \frac{2.0}{2.2} \Omega$$



- ii. (1pt) What is the peak current through LED1?

$$1.5V/\Omega \text{ across } 20\Omega \\ = 1.5/2 = 7.5mA$$

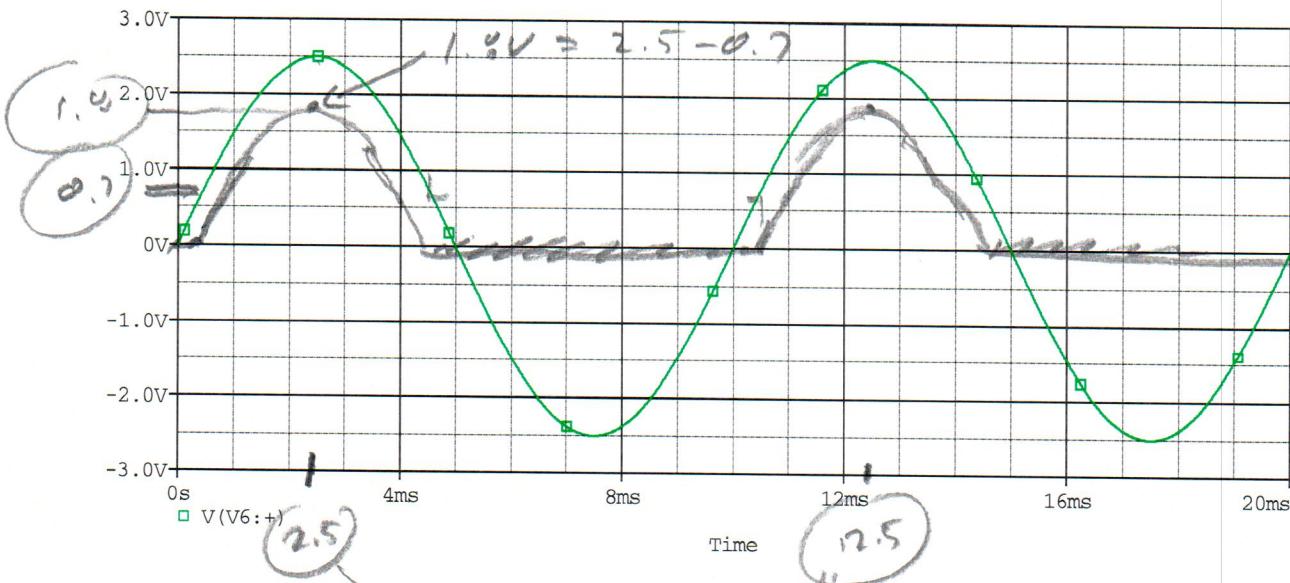
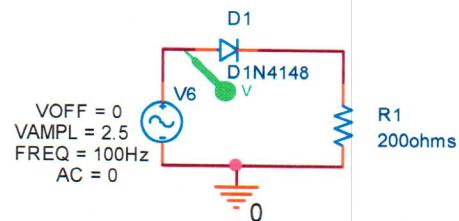
- iii. (1pt) What is the peak current through LED2?

$$2.8V/\Omega \text{ across } 20\Omega$$

$$\frac{2.8}{0.2} = 14mA$$

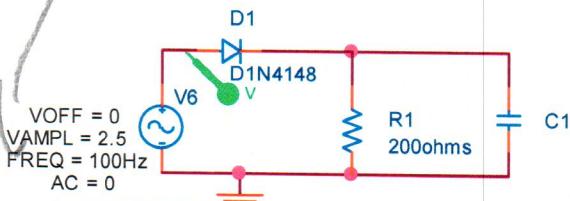
- c. Rectifier diodes: R1 is the load. The voltage across R1 is the output voltage. The plot shows the input voltage. Plot the output voltage using the Von diode model. Label important voltages. (3pts)

0.7 V drop



- d. A filter capacitor has been added to the circuit in part c. The plot for part c may be helpful for these questions.

- i. Give 2 times in plot c (time in ms on the plot) where the voltage on the capacitor would be at a maximum value. What are the times and what is the peak voltage? (2pts)



$2.5\text{ms}, 12.5\text{ms}$

- ii. What is the current in the resistor when the voltage on the capacitor is at the peak value? (1pt)

$$V = 1.8V \quad R = 100\Omega \quad I = \frac{1.8}{0.1} = 18mA$$

- iii. Immediately after when the voltage peaks on the capacitor, the diode will become reversed biased and will turn off. All of the current in R1 at this time must be supplied by C1. If C1=100uF, what is the dV/dt for the capacitor at this time? The Crip Sheet for Quiz 1 may be useful. (2pts)

$$I = C \frac{dV}{dt} \quad \frac{dV}{dt} = \frac{I}{C} = \frac{0.018}{10^{-4}} = 1800 \text{ V/sec} = \frac{dV}{dt}$$

- iv. Do a crude estimate of the ripple voltage by assuming that the dV/dt in part iii. is constant between voltage peaks from part i. This is a crude approximation. (1pts)

$$\Delta V \approx \frac{dV}{dt} \cdot \Delta t = (1800)(0.0125 - 0.0025) = 0.9V \text{ ripple}$$

$\uparrow \quad \uparrow$
 t_{peak}